

Prospects of proton and ion microbeams for radiation hardness testing

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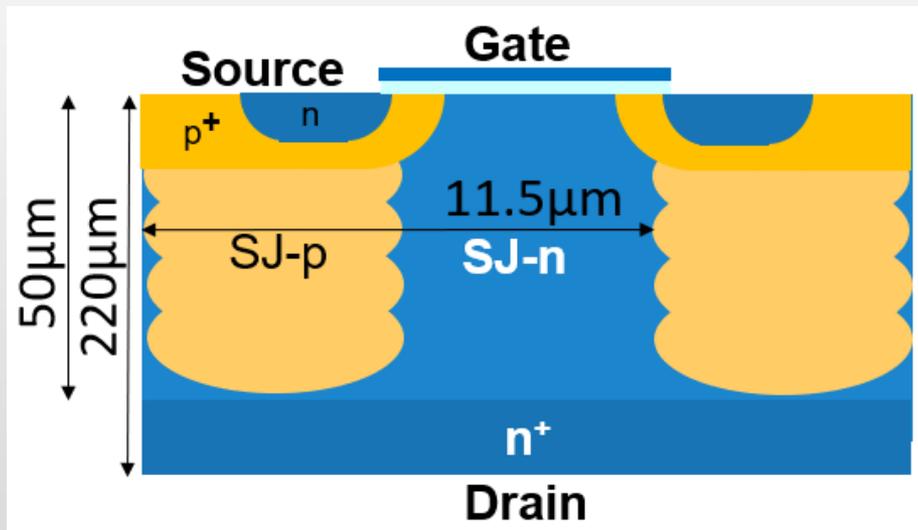
- 1) LRT 2, Universität der Bundeswehr München, Germany
- 2) Ernst Albrecht Hochschule, Jena, Germany

Content

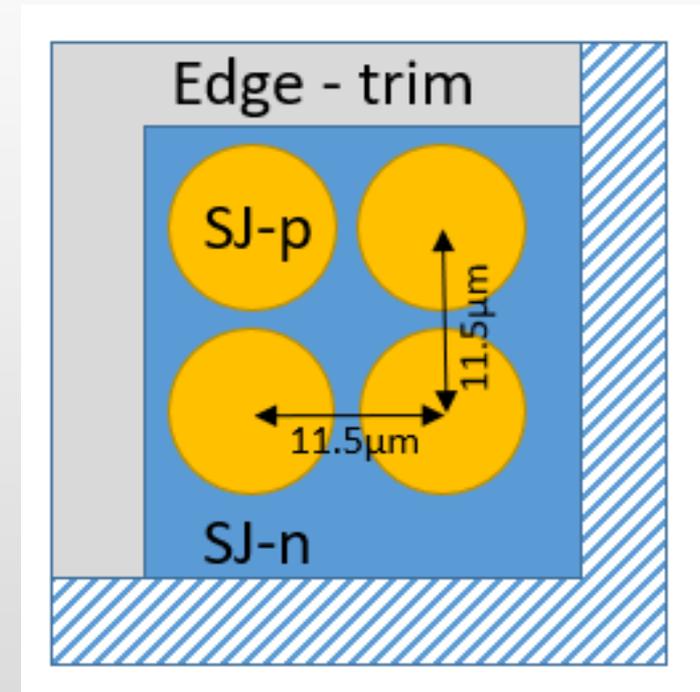
- What do we not know from conventional radiation hardness testing?
- How does an ion microprobe work?
- Ion microprobes in radiation hardness testing:
what can we learn?
- Micrometer focused, nanosecond proton bunches: a surrogate for heavy ion hardness testing ?

Vertical Silicon Superjunction MOSFET (Si-SJ-MOSFET)

- High voltage blocking capability;
- High current



Cross sectional view (x-z-plane)

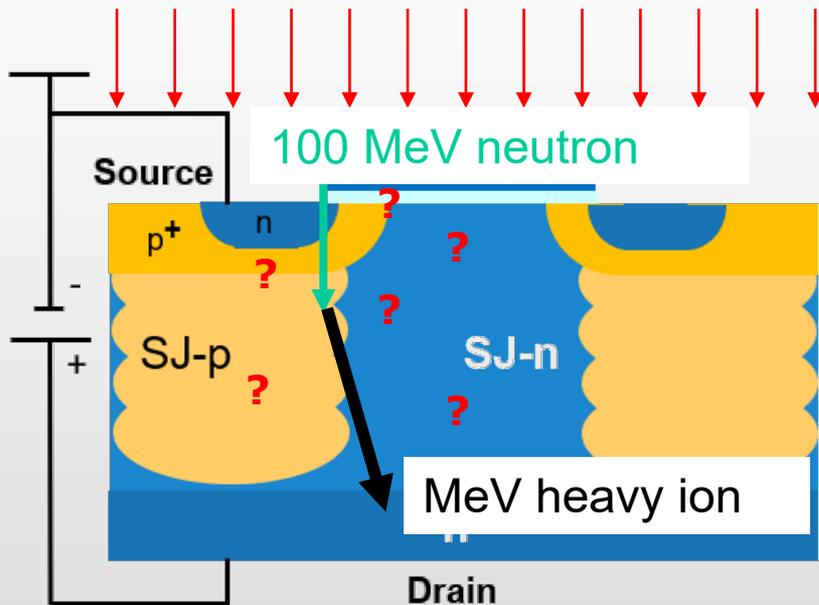


Top view (lateral x-y-plane)

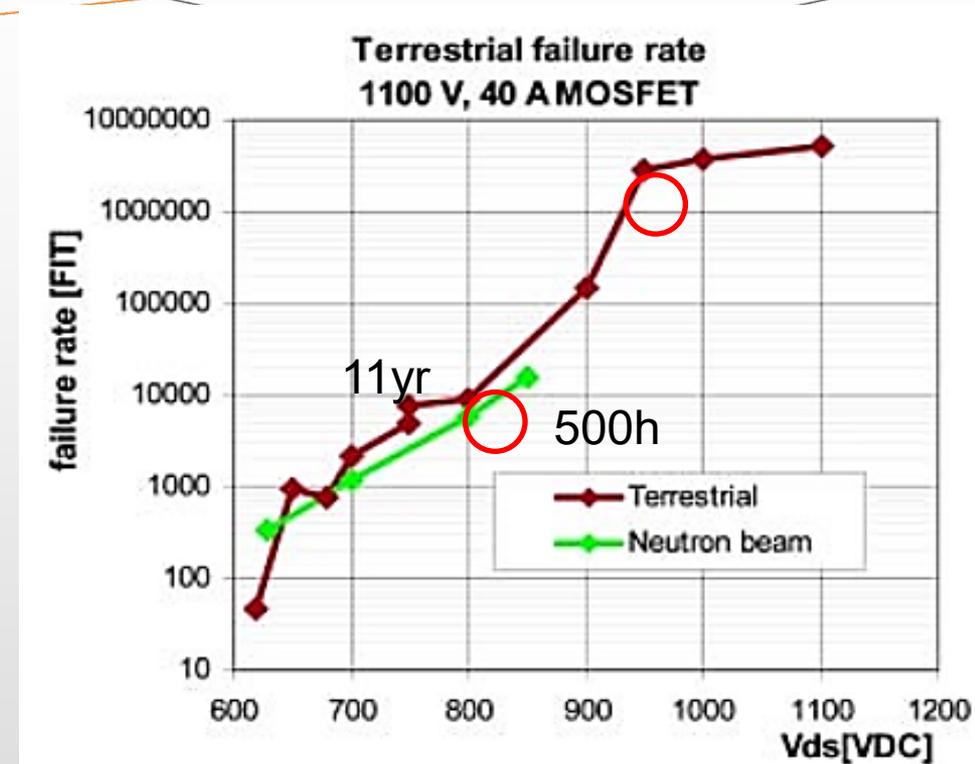
M. Gerold et al., *Microelectronics Reliability*, 155 (2024) 115309
M. Gerold et al., IEEE, 2018, doi: 10.1109/IPFA.2018.8452587.

Failure Rate Testing: State of the art radiation hardness testing

Atmospheric Neutrons



- Voltage derating necessary
- sensitive areas and dynamics of the failure?
- Main reactions: heavy ion recoils from high energy neutrons
- Heavy ion microbeams to get knowledge on sensitive areas?



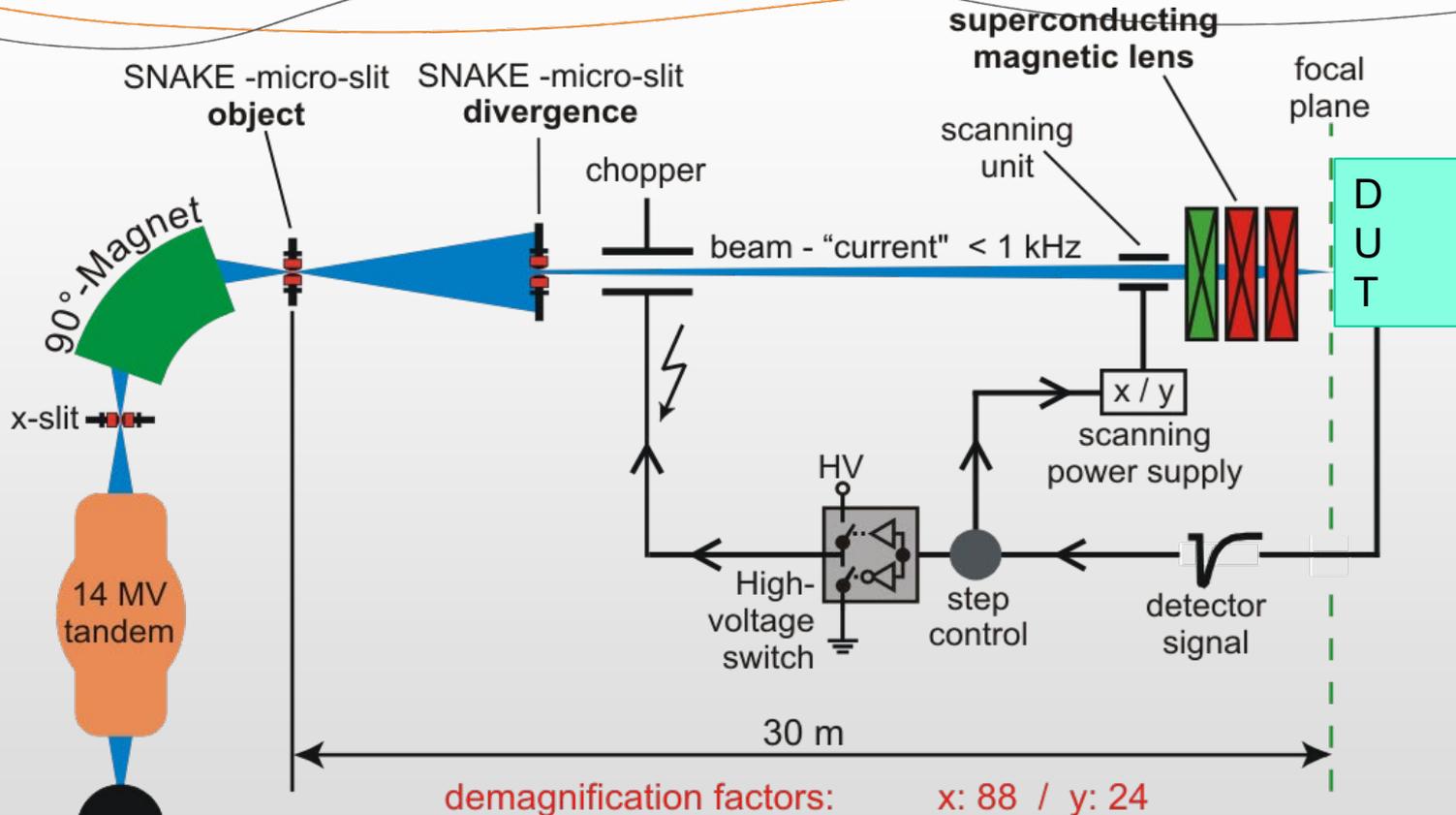
Lomonova et. al, Bodo's Power System Dec. 2011

M. Gerold et al., *Microelectronics Reliability*, 155 (2024) 115309

M. Gerold et al., IEEE, 2018, doi: 10.1109/IPFA.2018.8452587.

What is an ion microprobe here: the former SNAKE facility

Superconducting Nanoscope for Applied nuclear (Kern-) physics Experiments



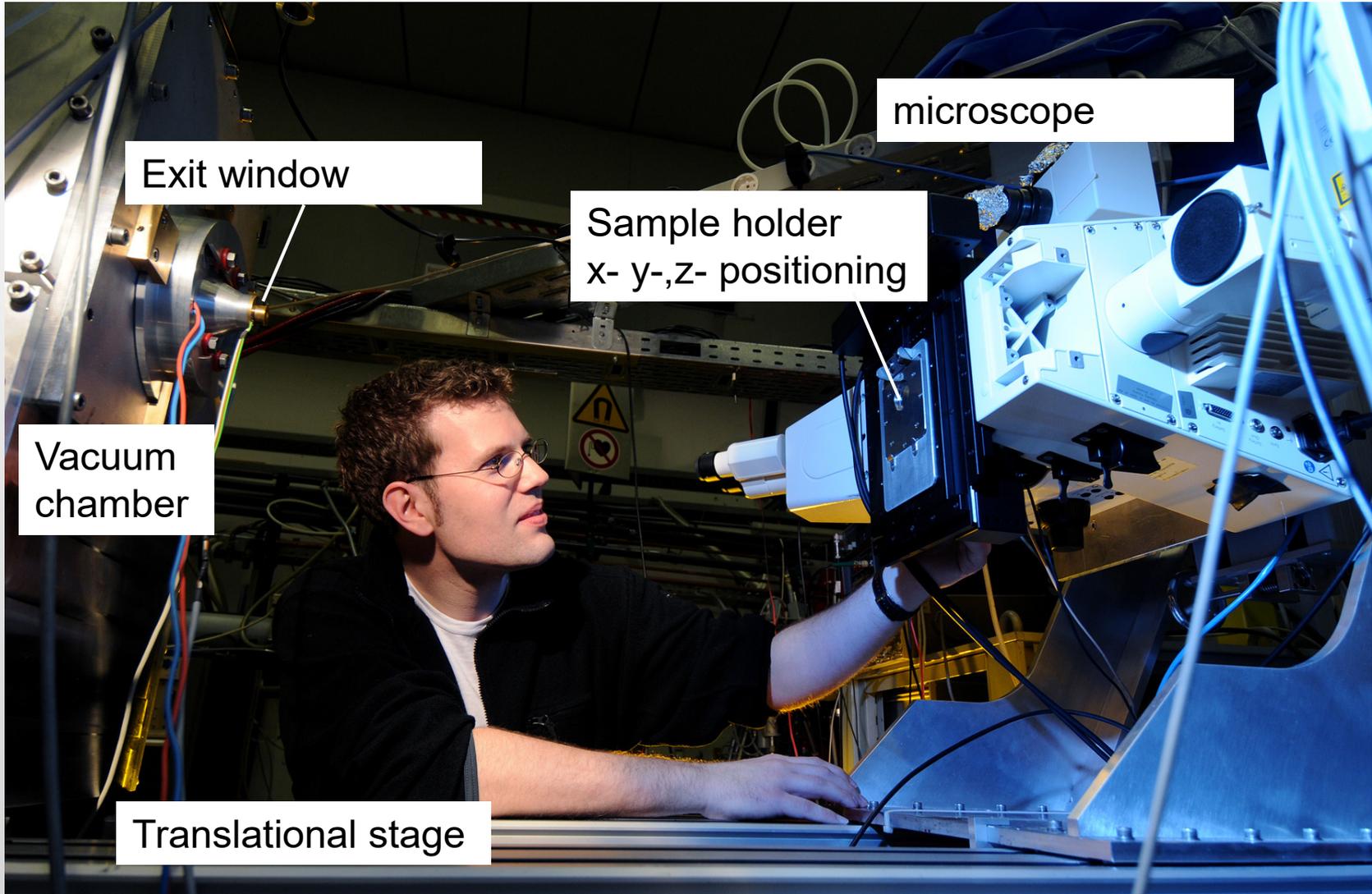
➤ Protons, 4 -28 MeV

➤ Beam resolution $\approx 0.5\ \mu\text{m}$ (fwhm)

➤ heavy ions – 200 MeV

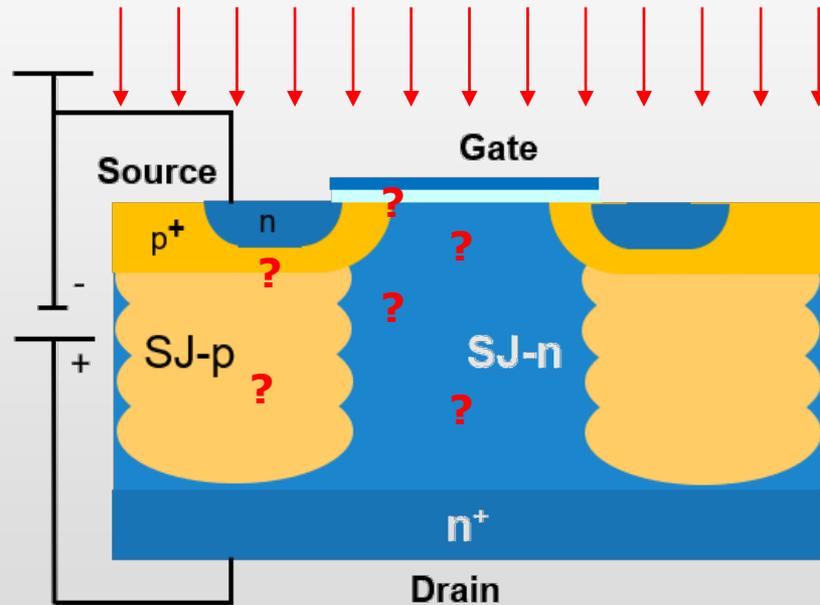
➤ Single ion irradiation facility

Sample environment in air, or alternatively in vacuum



Charge collection from heavy ion irradiation Si-Superjunction MOSFET

Focused, single 55 MeV ^{12}C -ions
(37.5 MeV Drift Region), LET 2.3 - 4.0 MeV cm^2/mg

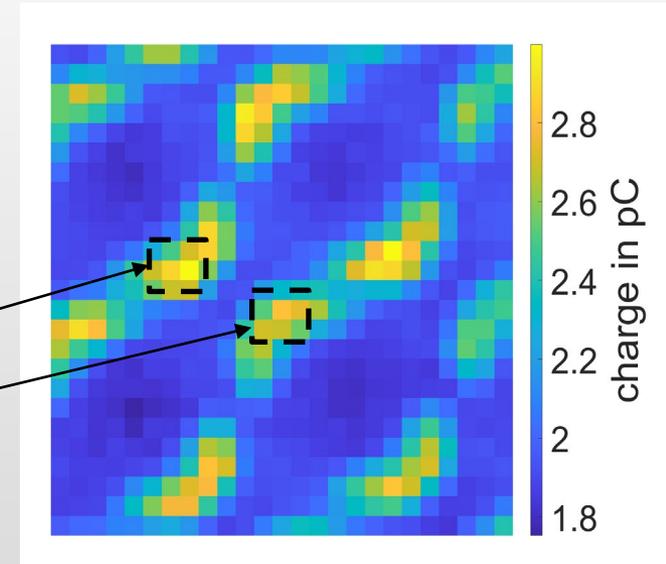
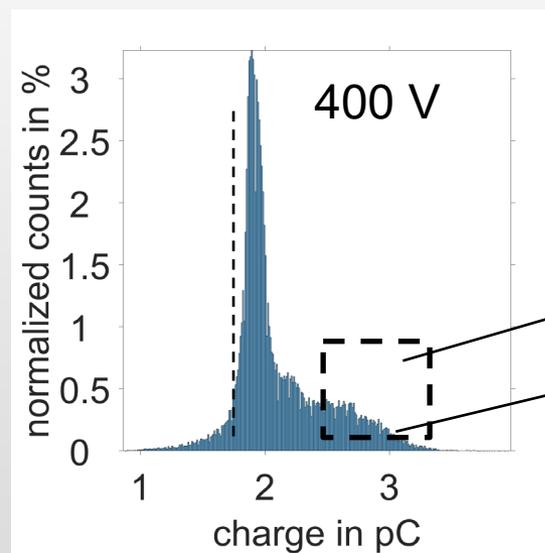
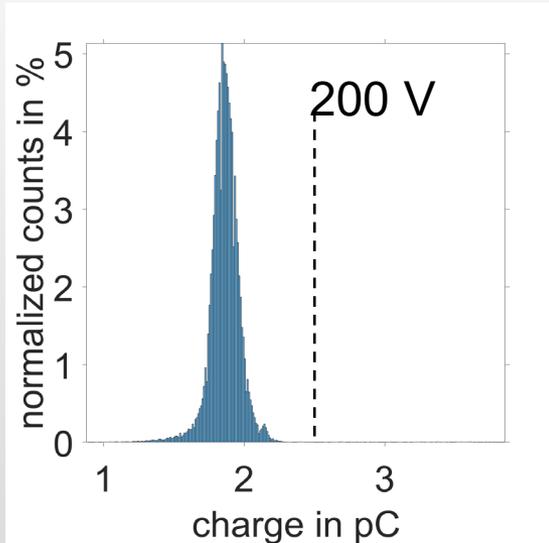


Ion mapping in dependence of voltage Si-SJ-MOSFET

- 55 MeV Carbon
- Expected charge collection: 1.7 pC

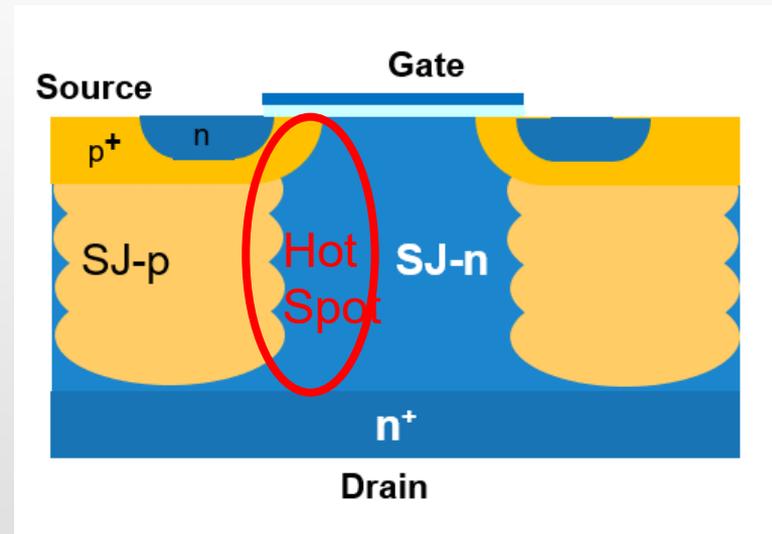
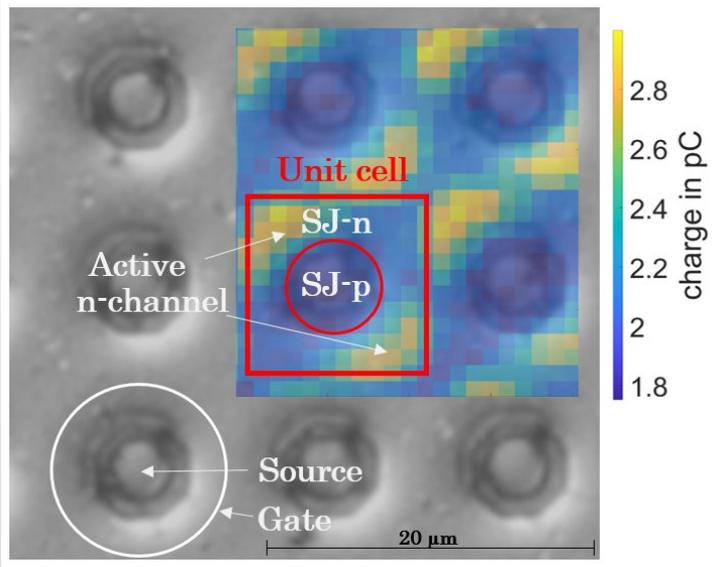
Charge collection spectrum

25x25 μm charge collection map



- Amplification at symmetric spots at 400 V

Ion Mapping Results: Sensitive Locations



- Pattern evolves from 200V to 400V (SOA)

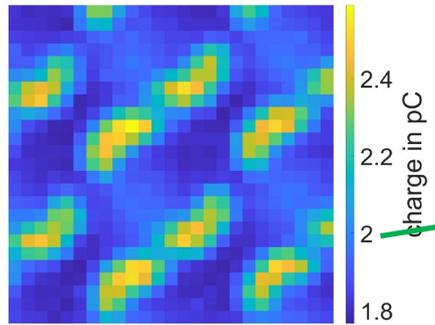
Ion Mapping: Partial Penetration of Drift Region

C, Max LET 5.2 MeV cm²/mg

S, Max LET 17.2 MeV cm²/mg

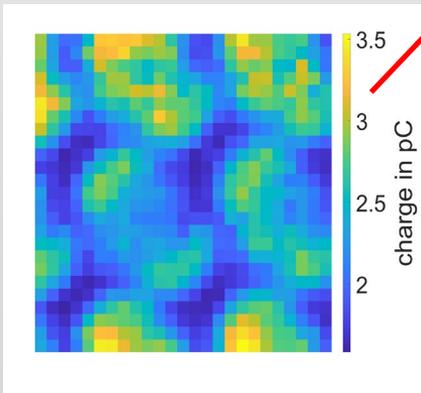
55 MeV ¹²C

400 V, 55 MeV C, Ion range 42 μm

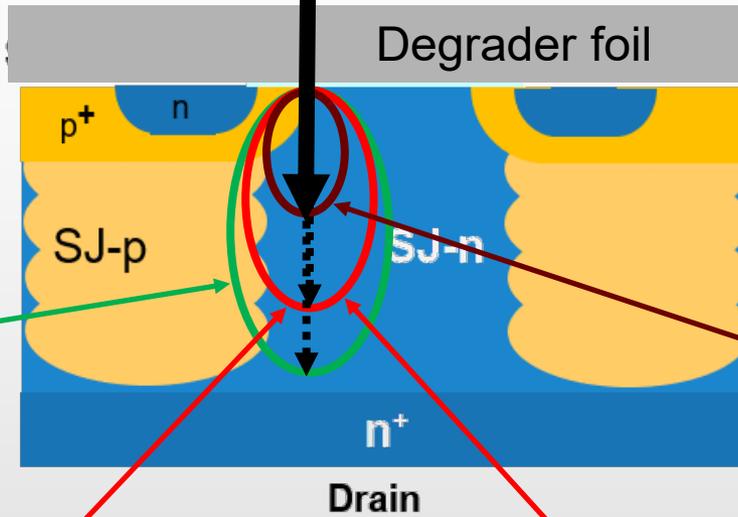


mean sensitivity x1.5

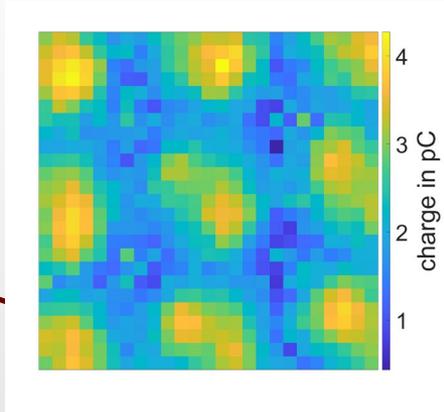
400 V, 27 MeV C, range 29 μm



mean sensitivity x2.2

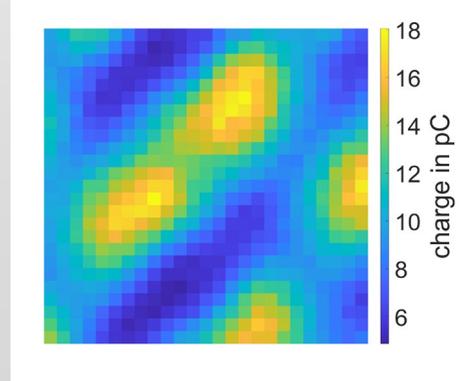


400 V, 14 MeV C, Ion range 13 μm



mean sensitivity x6.7

370 V, 110 MeV S, Ion range 26 μm



mean sensitivity x4.5
Base sensitivity x1.5

Single Event Transients (SET) in 65 nm CMOS IC GSI-Microbeam, 946 MeV Au (LET = 95 MeV cm²/mg)

M. Mitrovic, M. Hofbauer et al

IEEE TRANSACTIONS ON NUCLEAR SCIENCE, VOL. 64, NO. 8, AUGUST 2017

Spacing 0.12 μm
Pitch 0.5 μm

Spacing 0.25 μm
Pitch 0.63 μm

Spacing 2 μm
Pitch 2.38 μm

Spacing 4 μm
Pitch 4.38 μm

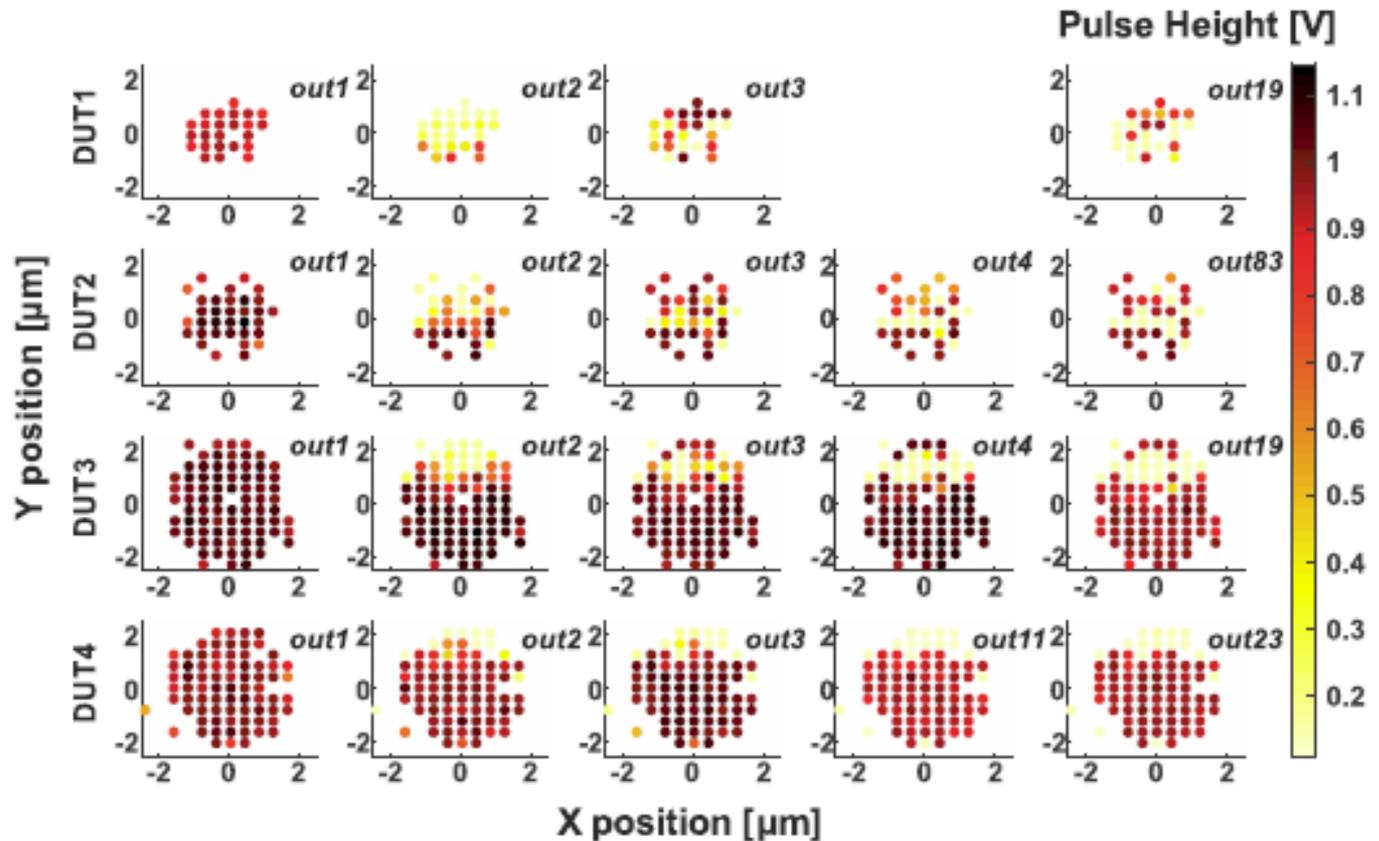
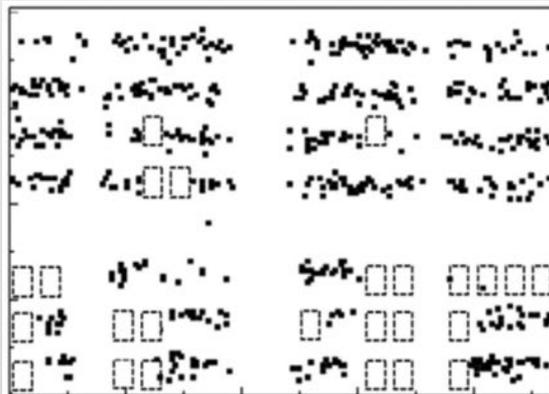
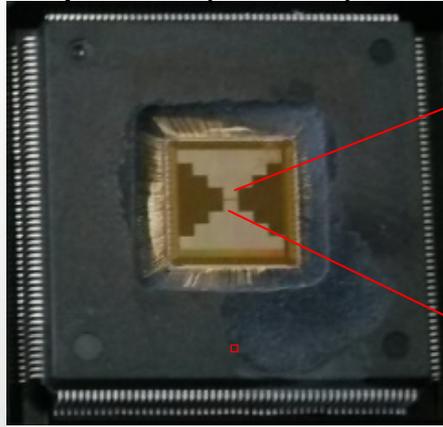


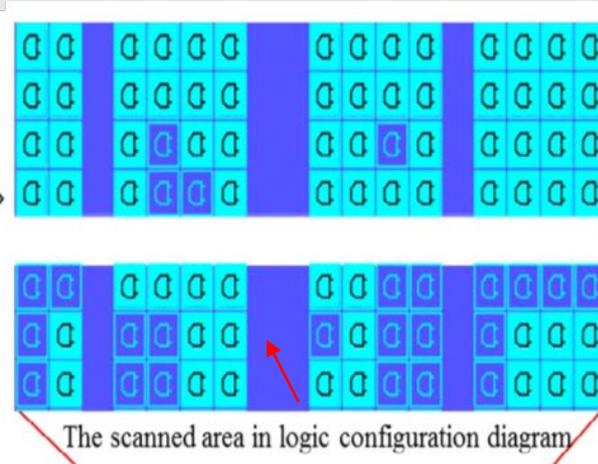
Fig. 8. Distribution of pulse heights for direct-hit SETs generated at the first inverter by ¹⁹⁷Au ions as a function of ion hit position, observed along the propagation through the chain.

Configure register of an **FPGA**, installed in Dark Matter Particle Explorer satellite-DAMPE

Lanzhou microprobe (China): here 25 MeV/nucl Kr-ions, LET=18.8 MeV cm²/mg



SEU image of configured DFFs in scanned area



The scanned area in logic configuration diagram

Individual bits without written data

IEEE TNS 69:890-899(2022)

In courtesy Guanghua Du, Lanzhou

NIMB 404:250-253 (2017)

Some Heavy Ion Microprobes

- **SNAKE, Munich/Germany, 14 MV tandem, no longer available**
- GSI microprobe, Darmstadt/Germany, < 11 MeV/nucl, all heavy ions
- Helmholtz Zentrum Dresden Rossendorf (HZDR) 6 MV Tandem (under construction)
- Ruder Boscovic, Zagreb/Croatia, 6 MV Tandem
- Lanzhou, China, (cyclotron, e.g. 25 MeV/nucl Ar, Kr)
- ANSTO Sydney, 10 MV tandem
- JAERI, Takasaki, Japan
- Sandia national lab, (not in operation at the moment)

- Others?

Linear Energy Transfer (LET) of Various Ions

LET in silicon

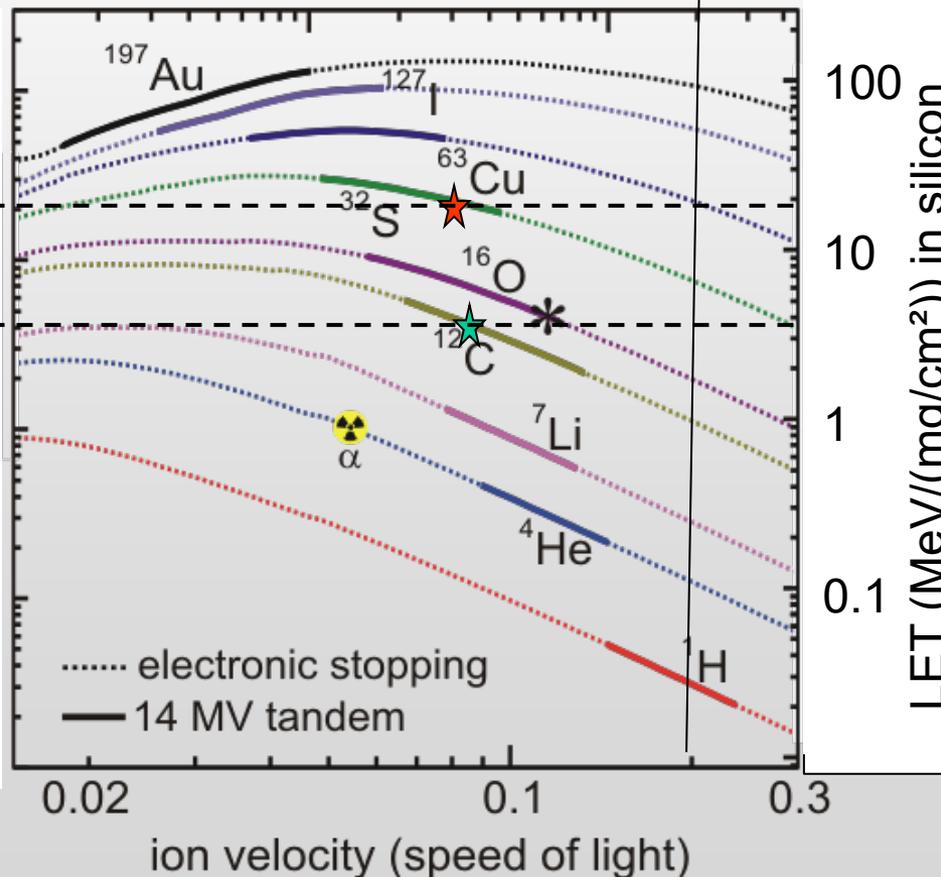
ion energy (MeV / u)

1 10

LET of 117 protons (20 MeV) equals
LET of 1 carbon ion (55 MeV)

110 MeV ^{32}S

55 MeV ^{12}C



- Terrestrial neutrons:
Recoil ions in
Si or SiC have $A < 31$
- ⇒ ^{32}S ions upper limit?
- ⇒ In space also heavier
ions,
- ⇒ but most protons up to
 $A < 58$



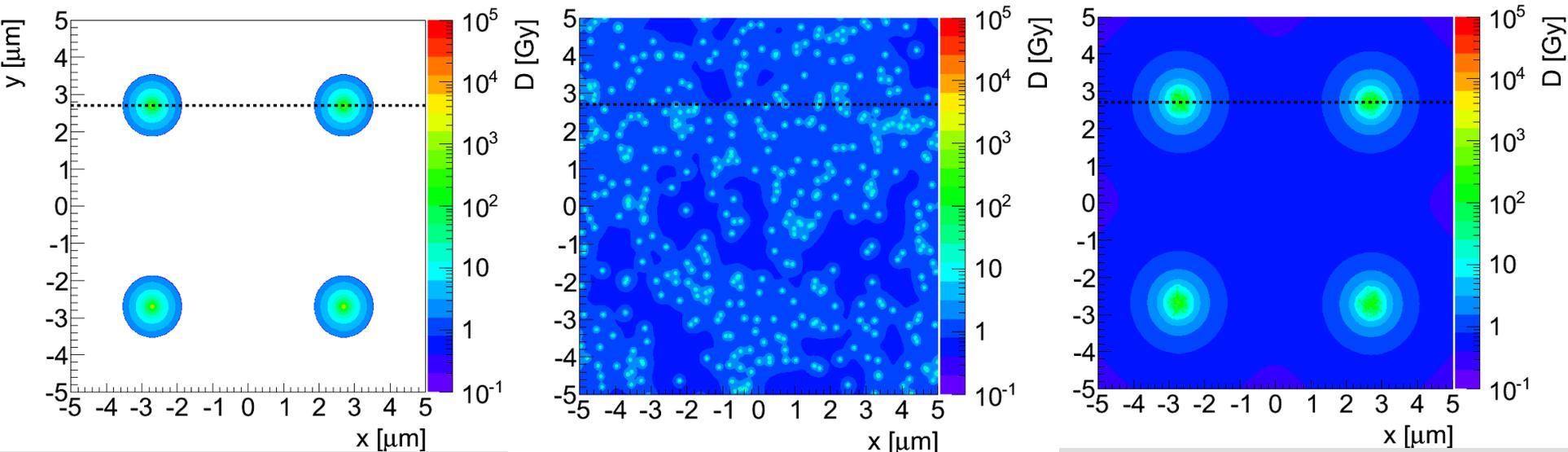
Bunched Protons as a Heavy ion surrogate?

- Only a few facilities offer heavy ions of sufficient range
- A new ansatz:
 - Focus a bunch of 5 – 25 MeV protons (100 – 1000)
 - In time (\sim ns)
 - In space ($< 1 \mu\text{m}$) (microprobe!) **not easy!**
 - ⇒ Same LET as very heavy ions,
 - ⇒ range from 200 μm to $> 3 \text{ mm}$
 - ⇒ Available at medium sized tandem accelerators with bunching capabilities and ion microprobes?

Bunched protons microdose distributions

LET (117 protons (20 MEV)) = LET (55 MeV carbon) = 304 keV/ μm in water

1.7 Gy average dose



55 MeV carbon ions

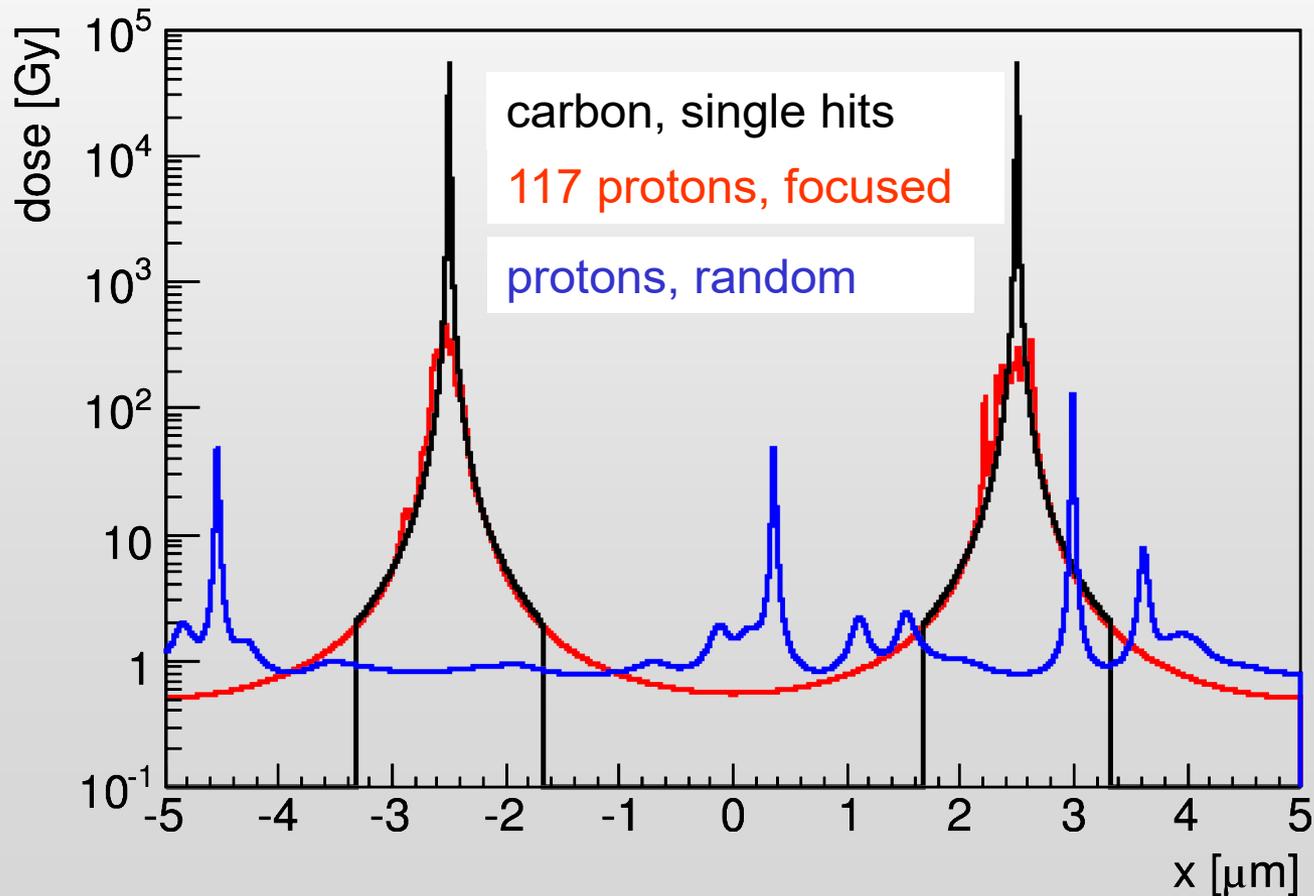
20 MeV protons,
Randomly distributed

20 MeV protons,
117 protons per focus
300 nm diameter

Comparison of bunched protons to carbon ions

LET (117 protons (20 MEV)) = LET (55 MeV carbon) = 304 keV/ μm in water

1.7 Gy average dose



carbon, single hits
117 protons, focused
protons, random

matrix $5 * 5 \mu\text{m}^2$
matrix $5 * 5 \mu\text{m}^2$
300 nm focus

Conclusion

- Heavy ion microprobes:
 - Analyse areas in micro-electronics sensitive to heavy ions
 - Experienced people and longer experimental time needed
 - Only a few microbeams available world wide
 - Limited range of available heavy ion beams at many accelerator centers
 - Proposal:
 - bunched protons in space and time
 - as a surrogate of high energy heavy ion (micro) beams
 - Needs smaller accelerators but pulsed microbeams!?